

Nano-scale Thermoelectric Materials for Solid-State Cooling and Direct Thermal-to-Electric Energy Conversion

Rama Venkatasubramanian, Brooks O'Quinn, Edward Siivola, Kip Coonley, Mary Napier, and Pratima Addepalli Center for Thermoelectrics Research

> Research Triangle Institute Research Triangle Park, North Carolina

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Outline

- Thermoelectrics Overview
 - Background
 - Material and Device Results
- Nano-scale Materials Technology Overview
 - Recent Results in Transitioning the Materials Breakthrough
 - Solid-state Cooling Applications
 - Thermal Management for Electronics

 Advanced System-Level Concepts to further leverage nano-materials advancements

- Thermal to Electrical Energy Conversion
- Potential with Nano-scale Materials



Thermoelectrics



Solid-State Technology

- Solid-state Reliability
- No Moving Parts
- Vibration/Noise free

CFC-free

Heat or Cool

Thermal Management

- Power Generation
- Thermal control functions

Chemistry, Biology,Physics

In 1960's, semiconductor thermoelectrics were considered to replace mechanical refrigerators and diesel-generators!!

- > Hope back then if transistors can replace vacuum tubes for electronics!
- Biggest problem then materials efficiency or figure-of-merit (ZT)
 - Had to improve from ~0.9 to 3 or higher
 - Identified as a Key Military Technology again in 1992

Vew Materials, especially nano-structures to the rescue?



What makes a good Thermoelectric Material?

• Figure of Merit = ZT = $(\alpha^2 \sigma/k)T$

- T = Absolute Temperature
- > α^2 = (Seebeck coefficient)²
 - Tells how much average thermal energy is transported by each carrier
- $\succ \sigma$ = electrical conductivity
 - Tells how much the carriers can transport energy without Joule loss
- k = thermal conductivity
 - Tells how small is the reverse flow of heat from the cold-side to the hot-side, opposing the electron-transport of heat
- <u>Minimize</u> thermal conductivity and <u>maximize</u> electrical conductivity
 - Has been the biggest dilemma for the last 40 years
 - Can the conflicting requirements be met by nano-scale material design?





The Big Challenge





Some of the Approaches

- New Bulk Materials
 - Skutterudites (Rensselaer, Oak Ridge, JPL, 1992)
 - Cage-structures with rattling atoms to scatter phonons
 - Novel Chalcogenides and Clathrates (Michigan State and Arizona, 1994)
 - Complex Variations of Bi₂Te₃ to reduce phonon mean-free paths
- Nano-scale Materials
 - Low-Dimensional Structures (MIT, MIT Lincoln Labs, 1992)
 - Quantum-confinement to Enhance Density of states which increase Seebeck coefficient
 - Nano-scale Superlattices (RTI, 1992)
 - Phonon-blocking from acoustic mismatch between superlattice components but electron-transmitting due to negligible electron-energy offsets
 - Heterostructure Thermionics (UCSB, Oak Ridge, 1996)
 - Thermionic-like effects using energy barriers that can be controlled in hetero-structures



Some Bulk Material and Nano-Material Progress

Cs Bi₄Te₆ (Michigan State University)

Bulk Materials with a <u>ZT~ 0.8 at 225K but less than 0.8 at 300K</u> (Science **287**, 1024-1027, 2000)

Filled Skuterrudites (JPL)

Bulk materials with a <u>ZT ~1.35 at 900K</u> (Proc. Of 15th International Conf. On Thermoelectrics, 1996)

PbTe/PbTeSe Quantum-dots (Harman, MIT Lincoln Labs.)

ZT~ 1.6 at 300K based on cooling data (Science 297, Sep. 2002)

Bi₂Te₃/Sb₂Te₃ Superlattices (RTI)

<u>ZT~2.4 at 300K</u> in devices with all properties measured at the same place, same time, with current flowing and verified by two independent techniques (*Nature*, 597-602, Oct. 2001)



Nano-structured Superlattice Material



- 10Å/50Å Bi₂Te₃/Sb₂Te₃
 Structure
- Optimized for disrupting heat transport while enhancing electron transport perpendicular to the superlattice interfaces

Applied Physics Letters, 75, 1104 (1999)

Growth of Superlattices





Applied Physics Letters, 75, 1104 (1999)

- Low-temperature growth needed
 - To enable formation of low-energy van der Waals bond along the growth direction (c-axis)
 - Allows growth of highly-lattice-mismatched structures without defects that can scatter carriers

Lattice-mismatch is preferred for acoustic-mismatch

In-situ ellipsometry for nanometer-scale control of deposition



Physics Behind ZT Enhancement

Ultra-low Cross-Plane Lattice Thermal Conductivity in Bi₂Te₃/Sb₂Te₃ Superlattices

Efficient Cross-Plane Hole Miniband Transport in Bi₂Te₃/Sb₂Te₃ Superlattices





Venkatasubramanian, Siivola, Colpitts, O'Quinn, Nature, 413, 597 (2001)

















HOT







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The RTI breakthrough arises from reducing heat transmission without disrupting electron flow

12 nanometer

















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HOT Bi₂Te₃ Sb₂Te₃ 12 nanometer COLD

HOT



HOT













































HOT



HOT





Finer Control of Structure/Period in Optimizing Both Phonon Blocking, Electron-Transmitting Structures



Physical Review B, 61, 3091 (2000)

Nature, 413, 597-602 (2001)



Big Jump in ZT with the Phonon-Blocking, Electron-Transmitting Structures



Venkatasubramanian, Siivola, Colpitts, O'Quinn, Nature, 413, 597 (2001)



 Enhanced efficiency compared to bulk TE element under similar test conditions



Nature, 413, 597 (2001)



- Enhanced efficiency
- Super-fast cooling and heating





- Enhanced efficiency
- Super-fast cooling and heating
- Enhanced cooling power density



- Enhanced efficiency
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- Enhanced cooling power density
- Localized cooling/ heating technology









Nature, 413, 597 (2001)

- Enhanced efficiency
- Super-fast cooling and heating
- Enhanced power density
- Localized cooling/ heating technology
- 1/40,000th the actual TE material requirement of bulk technology for same functionality – low recycle costs – Eco-friendly technology



Technology Overview

Recent Results in Transitioning the Materials Advancement

Progress in Thin-film P-N Couples – the fundamental cooling or power conversion unit for transitioning to modules





ZT ~ 2 at 300K

 The individual ZT of p- and n- SL materials has been transitioned to the ZT of couple



Thermal Management for Electronics
Superlattice Thermoelectrics: Also Useful for cooling hotspots in microprocessors - Match foot-print of Heat-load with that of Micro-Thermoelectric Devices





Pat Gelsinger, Intel CTOFebruary 5, 2001



Ref: www.intel.com



Thermal Management of High Heat Fluxes – Better Efficiencies at High Heat Fluxes with State-of-the-art Superlattice Devices





Better System Efficiencies Possible in the Thermal Management of Power Electronics That Switch Large Powers





 Potential Application of High Cooling Power Density to IGBT Chip Cooling – Automotive Power Electronics

- Most thermal management decided by hot-spots
- Cool the Hot-spots so that system-level cooling are lower



Advanced System-Level Concepts to further leverage nano-materials advancements

RTI's Superlattice Device on Cooling Efficiency

T_{HOT} = 300 K ΛT ~ 30 K



 Higher ZT – Incentives for New Approaches to Implement Higher COP Concepts like Novel Thermodynamic Cycles and Novel Heat-Transfer Approaches



Impact of New Heat Removal Schemes Combined with High ZT



Ref: Lon Bell (BSST, Division of Amerigon Inc.) - Pioneering Car-seat cooling and other auto climate control systems



TE Climate Control Technologies Available Today -Automotive Seat to Personal Space



Courtesy of BSST, Division of Amerigon Inc.

Cool/Heat Where You want - Higher System Efficiencies

Major Economic and Environmental Implications

Will Benefit from Higher ZT TE Materials



Direct Thermal-to-Electric Energy Conversion

- Compact Power Sources
- High Specific Power (Potentially 500 W/gm)
- High Power Density (Potentially 5 W/cm²)

Thermoelectric Power Conversion



$$\psi = \frac{(T_h - T_c)}{T_h} \frac{\{(1 + ZT)^{1/2} - 1\}}{(1 + ZT)^{1/2} - 1\} + T_c/T_h}$$

 Power Conversion Efficiency critically dependent on the material Figure of Merit (ZT)

• Maximize ΔT

➤ Thermal management (getting the heat out from the heat-sink) is important to generating the maximum ΔT

Power Conversion with Modules









Implications for Power

- Replace Batteries using Chemical-to-Thermal-to-Electrical Conversion







Impact of Light-weight, High-Efficiency Thermoelectric Technology with Waste-Heat Recovery





Further Possibilities with Nano-scale Thermoelectrics



Transitioning from Two-dimensional Superlattices to Onedimensional wires and Quantum-Boxes for Nano-scale Thermoelectrics

- Combine Phonon-Blocking, Electron-Transmitting Structures Along Heat Flow with Orthogonal Quantum-Confinement for ZT in the range of 4 to 5?



Layered SL Patterned to form 1-di Quantum-Wires – Orthogonal Quantum Confinement



Layered SL Patterned to form Quantum-Boxes – Orthogonal Quantum Confinement

